The RF Line **UHF Power Transistor**

 \dots designed primarily for wideband, large–signal output and driver amplifier stages to 1.0 GHz.

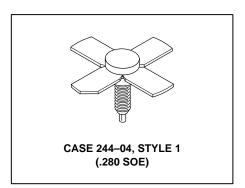
- Designed for Class A Linear Power Amplifiers
- Specified 25 Volt, 900 MHz Characteristics: Output Power — 1.5 Watts
 Power Gain — 8.0 dB Min, Class AB
- · Gold Metallization for Improved Reliability

MRF1029

1.5 W, TO 1.0 GHz LINEAR UHF POWER TRANSISTOR NPN SILICON

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	30	Vdc
Collector-Base Voltage	VCBO	60	Vdc
Emitter-Base Voltage	VEBO	4.0	Vdc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	14.5 0.084	Watts W/°C
Operating Junction Temperature	TJ	200	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C



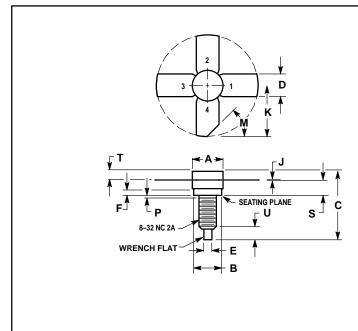
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (T _C = 70°C)	$R_{\theta JC}$	12	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (IC = 10 mA, IB = 0)	V(BR)CEO	30	_	_	Vdc
Collector–Emitter Breakdown Voltage (IC = 10 mA, VBE = 0)	V(BR)CES	60	_	_	Vdc
Collector–Base Breakdown Voltage (IC = 10 mA, IE = 0)	V(BR)CBO	60	_	_	Vdc
Emitter–Base Breakdown Voltage (I _E = 5.0 mA, I _C = 0)	V(BR)EBO	4.0	_	_	Vdc
Collector Cutoff Current (V _{CB} = 25 V, I _E = 0)	ICBO	_	_	1.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = 250 mA, V _{CE} = 5.0 V)	hFE	20	_	80	_
DYNAMIC CHARACTERISTICS					
Output Capacitance (V _{CB} = 28 V, I _E = 0, f = 1.0 MHz)	C _{ob}	_	_	4.75	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain (V _{CE} = 25 V, P _{out} = 1.5 W, f = 900 MHz, I _C = 0.2 A)	GPE	8.0	9.3	_	dB
Load Mismatch (V _{CE} = 25 V, I _C = 0.2 A, P _{Out} = 1.5 W, f = 900 MHz, Load VSWR = ∞:1, All Phase Angles)	Ψ	No Degradation in Output Power			

PACKAGE DIMENSIONS



	MILLIN	METERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	7.06	7.26	0.278	0.286	
В	6.20	6.50	0.244	0.256	
С	14.99	16.51	0.590	0.650	
D	5.46	5.96	0.215	0.235	
Е	1.40	1.65	0.055	0.065	
G	1.52		0.060		
J	0.08	0.17	0.003	0.007	
K	11.05		0.435		
M	45°	NOM	45°	5°NOM	
Р		1.27		0.050	
S	3.00	3.25	0.118	0.128	
T	1.40	1.77	0.055	0.070	
U	2.92	3.68	0.115	0.145	

PIN 1. EMITTER 2. BASE

3 EMITTER

4. COLLECTOR

CASE 244-04 ISSUE J

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